

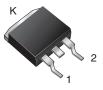
## MBRF20xxCT, MBRB20xxCT

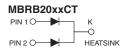
Vishay General Semiconductor

# **Dual Common Cathode Schottky Rectifier**

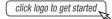
# ITO-220AB D<sup>2</sup>PAK (TO-263AB)







#### **DESIGN SUPPORT TOOLS**





PIN 3 O

PRIMARY CHARACTERISTICS					
I <sub>F(AV)</sub>	2 x 10 A				
V <sub>RRM</sub>	35 V, 45 V, 60 V				
I <sub>FSM</sub>	150 A				
V <sub>F</sub>	0.57 V, 0.70 V				
T <sub>J</sub> max.	150 °C				
Package	ITO-220AB, D <sup>2</sup> PAK (TO-263AB)				
Circuit configuration	Common cathode				

#### **FEATURES**

Power pack





- · Low power loss, high efficiency
- Low forward voltage drop
- · High forward surge capability
- · High frequency operation
- Meets MSL level 1, per J-STD-020, LF maximum peak of 245 °C (for D2PAK (TO-263AB) package)
- Solder bath temperature 275 °C maximum, 10 s, per JESD 22-B106 (for ITO-220AB package)
- AEC-Q101 qualified
- Material categorization: for definitions of compliance please see www.vishay.com/doc?99912

#### TYPICAL APPLICATIONS

For use in low voltage, high frequency rectifier of switching mode power supplies, freewheeling diodes, DC/DC converters, and polarity protection application.

#### **MECHANICAL DATA**

Case: ITO-220AB, D2PAK (TO-263AB)

Molding compound meets UL 94 V-0 flammability rating Base P/N-E3 - RoHS-compliant, commercial grade Base P/NHE3 - RoHS-compliant, AEC-Q101 qualified Base P/NHE3\_X - RoHS-compliant, AEC-Q101 qualified ("\_X" denotes revision code, e.g. A, B, ...)

Terminals: matte tin plated leads, solderable

J-STD-002 and JESD 22-B102

E3 suffix meets JESD 201 class 1A whisker test, HE3 suffix meets JESD 201 class 2 whisker test

Polarity: as marked

Mounting Torque: 10 in-lbs maximum

<b>MAXIMUM RATINGS</b> (T <sub>C</sub> = 25 °C unless otherwise noted)							
PARAMETER		SYMBOL	MBRB2035CT	MBRB2045CT	MBRB2060CT	UNIT	
Maximum repetitive peak reverse voltage		$V_{RRM}$	35	45	60		
Working peak reverse voltage		$V_{RWM}$	35	45	60	V	
Maximum DC blocking voltage		$V_{DC}$	35	45	60	1	
Maximum average forward rectified current to	tal device		20				
at T <sub>C</sub> = 135 °C	er diode	I <sub>F(AV)</sub>	10				
Peak forward surge current 8.3 ms single half sine-wave superimposed on rated load per diode		I <sub>FSM</sub>	150			Α	
Peak repetitive reverse surge current per diode at $t_p$ = 2.0 $\mu$ s, 1 kHz		I <sub>RRM</sub>	1.0 0.5		0.5		
Voltage rate of change (rated V <sub>R</sub> )		dV/dt	10 000			V/µs	
Operating junction temperature range		$T_J$	-65 to +150			°C	
Storage temperature range		T <sub>STG</sub>	-65 to +175				
Isolation voltage (ITO-220AB only) from terminal to heatsink t = 1 min		V <sub>AC</sub>	1500			V	



# MBRF20xxCT, MBRB20xxCT

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<b>ELECTRICAL CHARACTERISTICS</b> (T <sub>C</sub> = 25 °C unless otherwise noted)							
PARAMETER	SYMBOL	TEST CONDITIONS		MBRB2035CT, MBRB2045CT	MBRB2060CT	UNIT	
Maximum instantaneous forward voltage per diode		I <sub>F</sub> = 10 A	T <sub>C</sub> = 25 °C	0.65	0.80		
	V <sub>F</sub> <sup>(1)</sup>	I <sub>F</sub> = 10 A	T <sub>C</sub> = 125 °C	0.57	0.70	V	
		I <sub>F</sub> = 20 A	T <sub>C</sub> = 25 °C	0.84	0.95		
		I <sub>F</sub> = 20 A	T <sub>C</sub> = 125 °C	0.72	0.85		
Maximum reverse current at DC blocking voltage per diode	I <sub>R</sub> <sup>(2)</sup>	Pated V	T <sub>C</sub> = 25 °C	0.1	0.15	m ^	
	I 'R (=)	I <sub>R</sub> <sup>(2)</sup> Rated V <sub>R</sub>	T <sub>C</sub> = 125 °C	15	150	mA mA	

#### Notes

 $^{(1)}$  Pulse test: 300  $\mu s$  pulse width, 1 % duty cycle

(2) Pulse test: pulse width  $\leq$  40 ms

THERMAL CHARACTERISTICS (T <sub>C</sub> = 25 °C unless otherwise noted)					
PARAMETER	SYMBOL	MBRF	MBRB	UNIT	
Typical resistance from junction to case per diode	$R_{ heta JC}$	5.0	2.0	°C/W	

ORDERING INFORMATION (Example)							
PACKAGE	PREFERRED P/N	UNIT WEIGHT (g)	PACKAGE CODE	BASE QUANTITY	DELIVERY MODE		
ITO-220AB	MBRF2045CT-E3/45	1.99	45	50/tube	Tube		
TO-263AB	MBRB2045CT-E3/45	1.35	45	50/tube	Tube		
TO-263AB	MBRB2045CT-E3/81	1.35	81	800/reel	Tape and reel		
ITO-220AB	MBRF2045CTHE3/45 1)	1.99	45	50/tube	Tube		
TO-263AB	MBRB2045CTHE3_A/P (1)(2)	1.35	Р	50/tube	Tube		
TO-263AB	MBRB2045CTHE3_A/I (1)(2)	1.35	I	800/reel	Tape and reel		

#### Notes

<sup>(1)</sup> AEC-Q101 qualified

<sup>(2) 35</sup> V device available in AEC-Q101 qualified D2PAK (TO-263AB) only

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### **RATINGS AND CHARACTERISTICS CURVES** (T<sub>C</sub> = 25 °C unless otherwise noted)

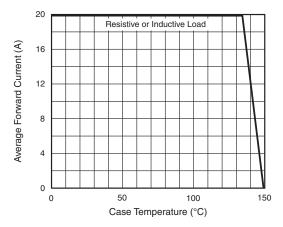


Fig. 1 - Forward Derating Curve (Total)

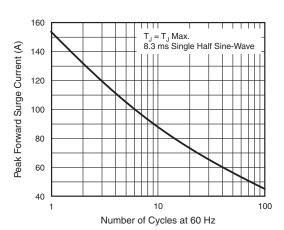


Fig. 2 - Maximum Non-Repetitive Peak Forward Surge Current Per Diode

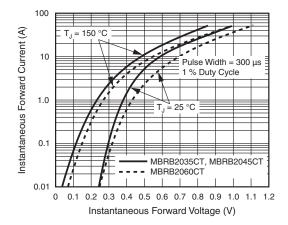


Fig. 3 - Typical Instantaneous Forward Characteristics Per Diode

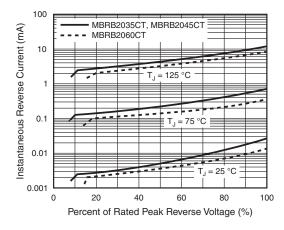


Fig. 4 - Typical Reverse Characteristics Per Diode

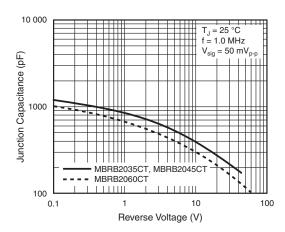


Fig. 5 - Typical Junction Capacitance Per Diode

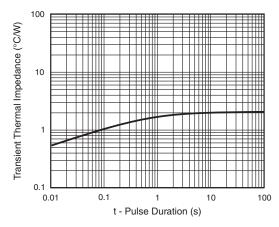
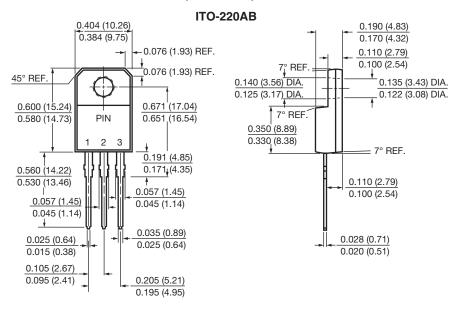


Fig. 6 - Typical Transient Thermal Impedance Per Diode

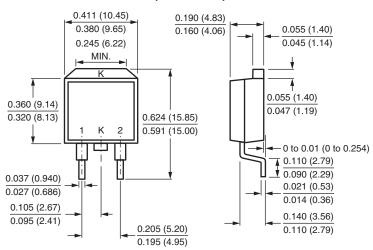


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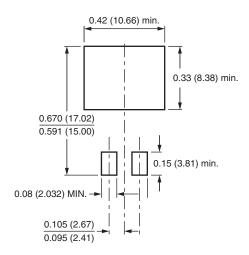
### **PACKAGE OUTLINE DIMENSIONS** in inches (millimeters)



### D<sup>2</sup>PAK (TO-263AB)



#### **Mounting Pad Layout**





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